

## Measurement Module for Strain Gage and LVDT/RVDT

Q.raxx slimline RS is Q.series' highest density 19" 1U rackmount DAQ system - the ideal solution for boom box installations or applications that require maximum channel density and custom sensor terminations. Q.raxx slimline RS DAQ systems utilize an external high-performance controller for communication, control, and data logging purposes. Multiple systems can be synchronized to each other allowing for efficient DAQ distribution with low jitter and gradual expansion up to thousands of channels. In addition to available variations, the Q.raxx slimline RS is fully customizable to your specific measurement needs.

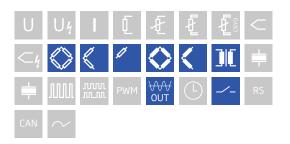
- RS485 fieldbus interface up to 24 Mbps
- Rack standard, 1 hight unit (1 HU)

- Power supply 10 up to 30 VDC
- Connectable to any Controller, e. g. Q.gate or Q.pac



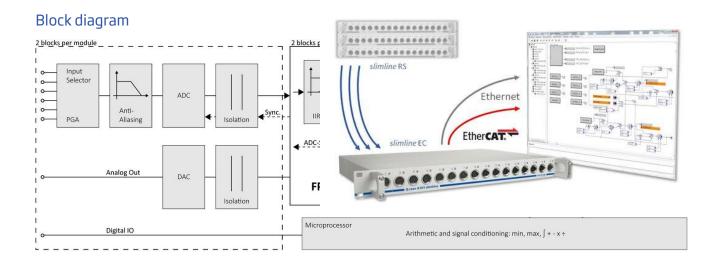
#### **Key Features**

- 8 Analog input channels strain gauge and inductive half and full bridges, LVDT, RVDT quarter bridge with completion terminal
- DC and carrier frequency (CF) principle 2.5 and 5 VDC excitation, 2.5 and 5 VDCeff excitation carrier frequency, 600 Hz or 4.8 kHz configurable per channel
- 8 Analog output channels ±10 VDC, 10 kHz update rate per channel
- High-accuracy digitization 24-bit ADC, 10 kHz sample rate per channel
- 4 digital I/Os input: state, tare, memory reset, output: state, alarm, threshold
- 16 Digital inputs or outputs status, trigger, tare, alarm, command
- Signal conditioning linearization, filtering, average, scaling, min/max, RMS, arithmetic, alarm
- 3-Way galvanic isolation Channel to channel, channel to power supply, and channel to bus



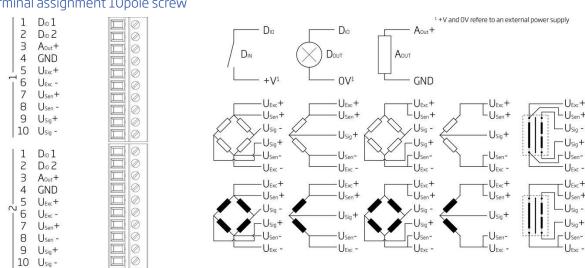


## Measurement Module for Strain Gage and LVDT/RVDT



#### **Technical Data**

## Terminal assignment 10pole screw



#### Analog Input Slimline

Channels	8
Accuracy	0.02 % typical
	0.05 % in controlled environment <sup>1</sup>
	0.1 % in industrial area <sup>2</sup>
Linearity error	0.02 % typical full-scale
Repeatability	0.01 % typical (within 24 hrs)
Input impedance	>10 MΩ
Isolation voltage	500 VDC channel to channel, to power supply, channel to bus <sup>3</sup>

 $<sup>^{\</sup>rm 1}$  according to EN 61326 2006: appendix B

<sup>&</sup>lt;sup>2</sup> according to EN 61326 2006: appendix A

<sup>&</sup>lt;sup>3</sup> noise pulses up to 1000 VDC, continuous up to 250 VDC



## Measurement Module for Strain Gage and LVDT/RVDT

## Strain Gage Measurement

Bridge configuration(s)	resistive full-bridge (4/6-wire) resistive half-bridge (3/5-wire) resistive quarter-bridge $120\Omega$ or $350\Omega$ (3-wire, with bridge completion terminal)			
Allowable sensor cable length	< 30 m			
Shunt resistor	100 kΩ internal resistor			
Bridge excitation	2.5 - 5 VDC 2.5 - 5 Veff (Carrier Frequency)			
Bridge excitation stability	<0.01% / 24 hrs			
Bridge excitation drift	<0.02%/10K			
	5 VDC	5 Veff (CF)	2.5 VDC	2.5 Veff (CF)
Allowable sensor resistance	>300Ω	>300 Ω	>100 Ω	>100 Ω
Input range	±1.25 mV/V	±1.25 mV/V	±2.5 mV/V	±2.5 mV/V
	±2.5 mV/V	±2.5 mV/V	±5 mV/V	±5 mV/V
	±25 mV/V	±25 mV/V	±50 mV/V	±50 mV/V
	±50 mV/V	±50 mV/V	±100 mV/V	±100 mV/V
	±100 mV/V	±100 mV/V	±200 mV/V	±200 mV/V
	±200 mV/V	±200 mV/V	±400 mV/V	±400 mV/V
	±500 mV/V	±500 mV/V	±1000 mV/V	±1000 mV/V
Long-term stability	<0.2 µV/V / 24 hrs (DC excitation) <0.1 µV/V / 24 hrs (CF excitation)		<2 μV/V / 8000 hrs	,
mperature drift (range 2.5 mV/V)	<0.2 µV/V / 10 K Offset drift		< 0.05 % / 10 K Gair	n drift
Noise (range 2.5 mV/V)	0.3 μV/V at 0 up to 10 Hz		1 μV/V at 10 up to 1	. kHz

#### LVDT/RVDT Measurement

4-/6-wire	
5 Veff	2.5 Veff
>300 Ω	>100 Ω
±1.25 mV/V	±2.5 mV/V
±2.5 mV/V	±5 mV/V
±25 mV/V	±50 mV/V
±50 mV/V	±100 mV/V
±100 mV/V	±200 mV/V
±200 mV/V	±400 mV/V
±500 mV/V	±1000 mV/V
<100 m <sup>1</sup>	
<0.1 µV/V / 24 hrs	<1 µV/V / 8000 hrs
<0.2 µV/V / 10 K Offset drift	< 0.05 % / 10 K Gain drift
<0.3 µV/V at 10 Hz	<1 μV/V at 100 Hz
	5 Veff >300 Ω ±1.25 mV/V ±2.5 mV/V  ±25 mV/V  ±25 mV/V  ±100 mV/V  ±100 mV/V  400 mV/V  <100 m¹  <0.1 μV/V / 24 hrs  <0.2 μV/V / 10 K Offset drift

<sup>1</sup> low capacity sensor cable is strongly recommended



## Measurement Module for Strain Gage and LVDT/RVDT

## Analog Output

Channels	2	
Accuracy	0.02 % typical	
Voltage output	±10 VDC	
Allowable load resistance	>2 kΩ	
Long-term drift	<1 mV / 24 hrs	<2.5 mV / 8000 hrs
Temperature drift	<1 mV /10 K Offset drift	< 0.05 % / 10 K Gain drift
Noise voltage	<2 mV at 10 Hz	<10 mV at 1 kHz

## Digital Input & Output

Channels	4 configurable I/Os
Mode(s) of operation	status
Logic voltage	<2 VDC (Low)
	>10 VDC (High)
Input type	PNP (current sinking)
Input voltage	30 VDC max.
Output voltage	10 to 30 VDC (external supply required)
Contact	open drain p-channel MOSFET
Load capacity	30 VDC / 100 mA (ohmic load)

## Analog to Digital Conversion

Resolution	24-bit
Sample rate	10 kHz per channel
Modulation method	sigma-delta
Anti-aliasing filter	2 kHz, 3rd order (DC excitation) 1 kHz, 3rd order (4.8 kHz CF excitation) 100 Hz, 3rd order (600 Hz CF excitation)
Digital filters	Infinite impulse response (IIR), low-pass, high-pass, band-pass, band-stop, to 8th order Butterworth or Bessel, frequency range 0.1 Hz to 1 kHz in steps of 0.1 (adjustable via software)
Averaging	configurable or automatic according to the user-defined data rate

## Digital to Analog Conversion

Resolution	16-bit
Update rate	10 kHz per channel
Settling time	Зµѕ

## Communication Interface

Protocols	proprietary Localbus (115200 bps to 24 Mbps, latency <100 ns) ASCII (19200 bps to 115200 bps) Modbus RTU Profibus-DP (19200 bps to 12 Mbps) (special Firmware required)
Data format	8E1
Electrical standard	ANSI/TIA/EIA-485-A, 2-wire



## Measurement Module for Strain Gage and LVDT/RVDT

## **Power Supply**

Input voltage	10 to 30 VDC, overvoltage and overcurrent protection
Power consumption	2.5 W (approx.)
Input voltage influence	<0.001%/V

## **Environmental Specifications**

Electromagnetic compatibility (EMC)	according to IEC 61000-4 and EN 55011
Operating temperature	-20°C to +60°C
Storage temperature	-40°C to +85°C
Relative humidity	5 - 95 % at 50°C (non-condensing)

#### Remarks

Are subject to a warm-up period of at least 45 minutes

in a controlled electromagnetic environment<sup>1</sup>

With configuration: Low-pass 10Hz2

Specifications subject to change without notice

#### Mechanical information

Туре	19" Standard, 1 Unit
Measurements (W x H x D)	444 x 44 x 260 mm
Weight	approx. 2000 g

## Ordering Information

Article number	868186

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 $<sup>^{\</sup>rm 1}$  according to EN 61326 2006: appendix B

<sup>&</sup>lt;sup>2</sup> according to EN 61326 2006: appendix A